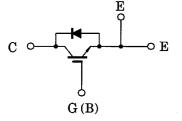
TOSHIBA GTR Module Silicon N Channel IGBT

MG200Q1US51

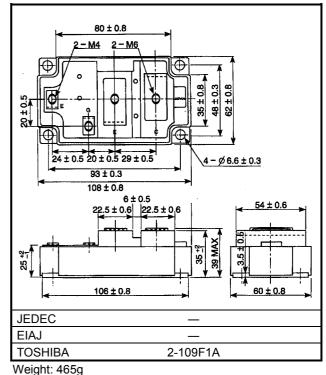
High Power Switching Applications Motor Control Applications

- High input impedance
- High speed: tf = 0.3µs (Max.) @Inductive load
- Low saturation voltage
 - $: V_{CE} (sat) = 3.6V (Max.)$
- Enhancement-mode
- The electrodes are isolated from case.

Equivalent Circuit



Maximum Ratings (Ta = 25°C)



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Characteristic		Symbol	Rating	Unit	
Collector-emitter voltage		V _{CES}	1200	V	
Gate-emitter voltage		V _{GES}	±20	V	
Collector current	DC	I _C (25°C / 80°C)	300 / 200	A	
	1ms	I _{CP} (25°C / 80°C)	600 / 400		
Forward Current	DC	١ _F	200	А	
	1ms	I _{FM}	400	A	
Collector power dissipation (Tc = 25°C)		P _C	1500	W	
Junction temperature		Tj	150	°C	
Storage temperature range		T _{stg}	-40 ~ 125	°C	
Isolation voltage		V _{Isol}	2500 (AC 1 min.)	V	
Screw torque (Terminal : M4/M6/mounting)		—	2/3/3	N∙m	

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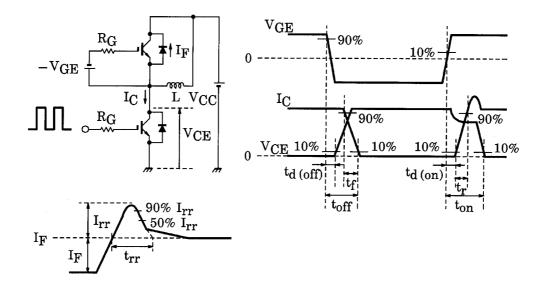
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Electrical Characteristics (Ta = 25°C)

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Characteristic		Symbol	Test Condition		Min	Тур.	Max	Unit
Gate leakage current		I _{GES}	$V_{GE} = \pm 20V, V_{CE} = 0$		_	_	±500	nA
Collector cut-off current		ICES	V _{CE} = 1200V, V _{GE} = 0		_	_	4.0	mA
Gate-emitter cut-off voltage		V _{GE (off)}	I _C = 200mA, V _{CE} = 5V		3.0	-	6.0	V
Collector-emitter saturation voltage		V _{CE (sat)}	I _C = 200A V _{GE} = 15V	T _j = 25°C	_	2.8	3.6	v
				T _j = 125°C	_	3.1	4.0	
Input capacitance		Cies	V_{CE} = 10V, V_{GE}	/ _{CE} = 10V, V _{GE} = 0, f = 1MHz		24.0	_	nF
Switching time	Turn-on delay time	t _{d (on)}	Inductive load $V_{CC} = 600V$ $I_C = 200A$ $V_{GE} = \pm 15V$ $R_G = 4.7\Omega$		_	0.05	_	- µs
	Rise time	tr			_	0.05	_	
	Turn-on time	t _{on}			_	0.2	_	
	Turn-off delay time	t _{d (off)}			_	0.5	_	
	Fall time	t _f		(Note 1)	_	0.1	0.3	
	Turn-off time	t _{off}			_	0.6	_	
Forward voltage		VF	I _F = 200A, V _{GE} = 0		_	2.4	3.5	V
Reverse recovery time		t _{rr}	I _F = 200A, V _{GE} = -10V di / dt = 700A / μs (Note 1)		_	0.15	0.3	μs
Thermal resistance		R _{th (j-c)}	Transistor stage		_	—	0.08	°C/W
			Diode stage		_	_	0.24	

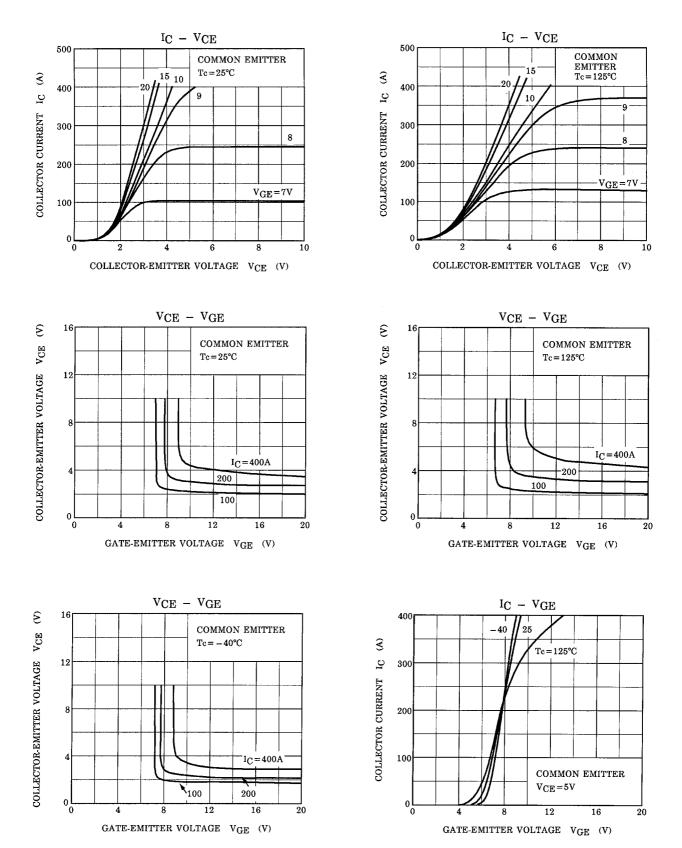
Note 1: Switching time and reverse recovery time test circuit & timing chart

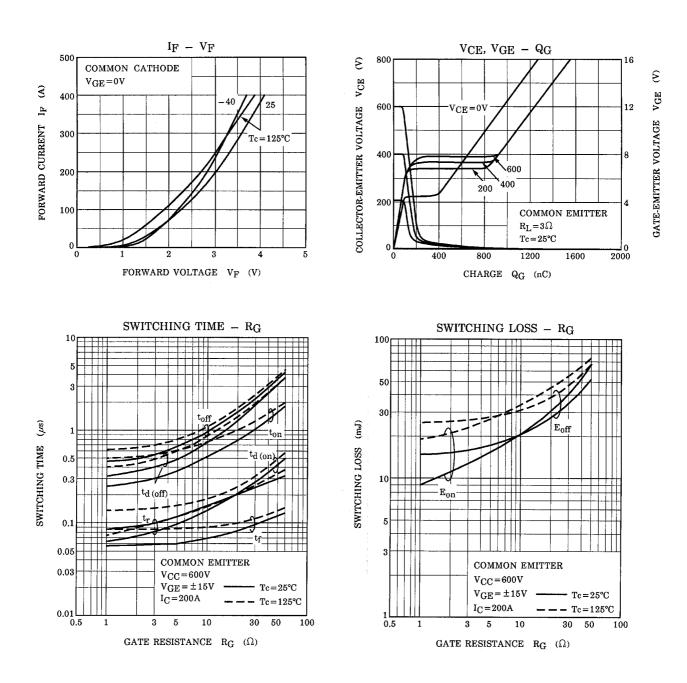


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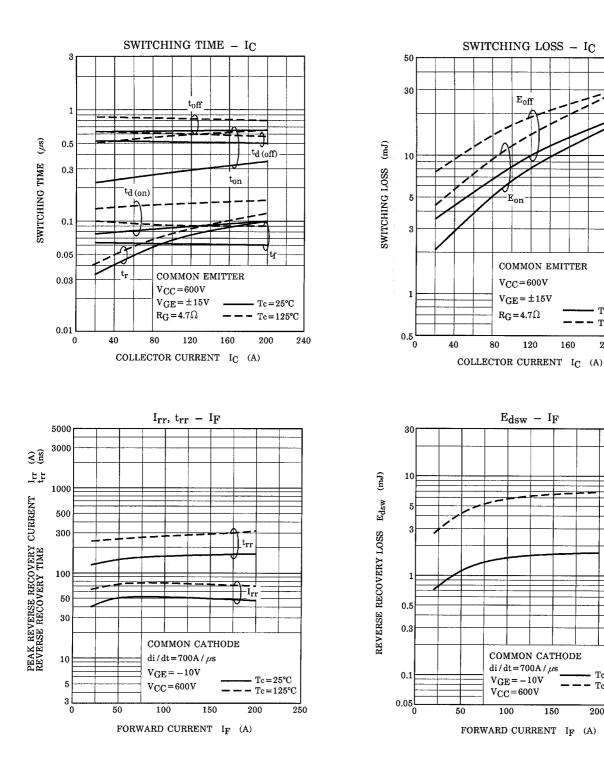


 $Tc = 25^{\circ}C$

- Tc=125°C

240

200



- Tc=25°C

250

-- Tc=125°C

200

